

## 1. 特点(Features)

- (1) 绝缘电压: (Isolation voltage between input and output)  $V_{iso} \cong 5,000V_{rms}$
- (2) 6脚可控硅光电隔离器 (6pin DIP optoisolators, triac driver output)
- (3) 符合欧盟 REACH 标准 (Compliance with EU REACH)
- (4) 产品符合 RoHS 要求 (The product itself will remain within RoHS compliant version)
- (5) 运行温度范围: (Operating temperature)  $-40^{\circ}C$  to  $+100^{\circ}C$

## 2. 说明 (description)

描述该系列器件包含一个红外发光二极管和光电探测器。不含卤素和  $Sb_2O_3$ 。

## 3. 应用范围 (Application Range)

- 交流电动机驱动 (AC Motor Drives)
- 交流电机启动器 (AC Motor Starters)
- 照明控制 (Lighting Controls)
- 电磁阀控制 (Solenoid/Valve Controls)
- 固态继电器 (Solid State Relays)
- 温度控制器 (Temperature Controls)

## 4. 最大绝对额定值(常温 $T=25^{\circ}C$ ) Max Absolute rated Value (Normal Temperature= $25^{\circ}C$ )

参数 Parameter		符号 Symbol	典型值 Rated Value	单位 Unit
输入 Input	正向电流 (Forward Current)	$I_F$	50	mA
	结温 (Junction Temperature)	$T_J$	125	$^{\circ}C$
	逆向电压 (Reverse Voltage)	$V_R$	6	V
	功率耗损 (Power Dissipation)	P	100	mW
输出 Output	断态重复峰值电压 (Off-State Output Terminal Voltage)	$V_{DRM}$	400	V
	峰值重复浪涌电流 (Peak Repetitive Surge Current) (PW=1ms, 120 pps)	$I_{TSM}$	1	A
	结温 (Junction Temperature)	$T_J$	125	$^{\circ}C$
	集电极功率耗损 (Collector Power Dissipation)	$P_C$	300	mW
总功率消耗 (Total Power Dissipation)		$P_{tot}$	330	mW
*1 绝缘电压 (Insulation Voltage)		$V_{iso}$	5000	$V_{rms}$
工作温度 (Working Temperature)		$T_{opr}$	$-40 \sim +100$	$^{\circ}C$
存贮温度 (Deposit Temperature)		$T_{stg}$	$-55 \sim +150$	
*2 焊锡温度 (Soldering Temperature)		$T_{sol}$	260	

\*1. 交流测试, 时间 1 分钟, R.H. =40~60% AC Test, 1 minute, humidity = 40~60%

如下是绝缘测试的方法. Insulation test method as below:

- (1) 将产品的两端短路。 Short circuit both terminals of photocoupler
- (2) 测试绝缘电压时无电流通过。 No Current when testing insulation voltage
- (3) 测试时加正弦波形电压。 Adding sine wave voltage when testing

\*2. 锡焊时间为 10 秒 soldering time is 10 seconds

5. 光电特性(常温 T=25°C) (Opto-electronic Characteristics)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min	典型值 Typ.*	最大 Max	单位 Unit
输入 (Input)	正向电压 (Forward Voltage)	$V_F$	$I_F=20mA$	---	1.2	1.6	V
	逆向电流(Reverse Current)	$I_R$	$V_R=6V$	---	0.05	10	$\mu A$
输出 (Output)	1.峰值阻断电流, 任一方向 (Peak Blocking Current, Either Direction)	$I_{DRM}$	$V_{DRM} = 400V$	---	10	100	nA
	峰值状态电压, 任一方向 (Peak On-State Voltage, Either Direction)	$V_{TM}$	$I_{TM}=100mA$ Peak	---	1.7	3.0	V
	2.断态电压临界上升率 (Critical rate of Rise of Off-State Voltage)	dv/dt	$V_{in}=240V_{rms}$	1000	---	---	V/us
组合 Couple	3.LED 触发电流, 锁存输出所需的电流, 任一方向 (Led Trigger Current, Current Required to Latch Output, Either Direction)	MOC3020	$I_{FT}$ Main Terminal Voltage = 3V	---	---	30	mA
		MOC3021		---	---	15	
		MOC3022		---	---	10	
		MOC3023		---	---	5	
	Holding Current, Either Direction		$I_H$		---	200	---

\*1. Test voltage must be applied within dv/dt rating.

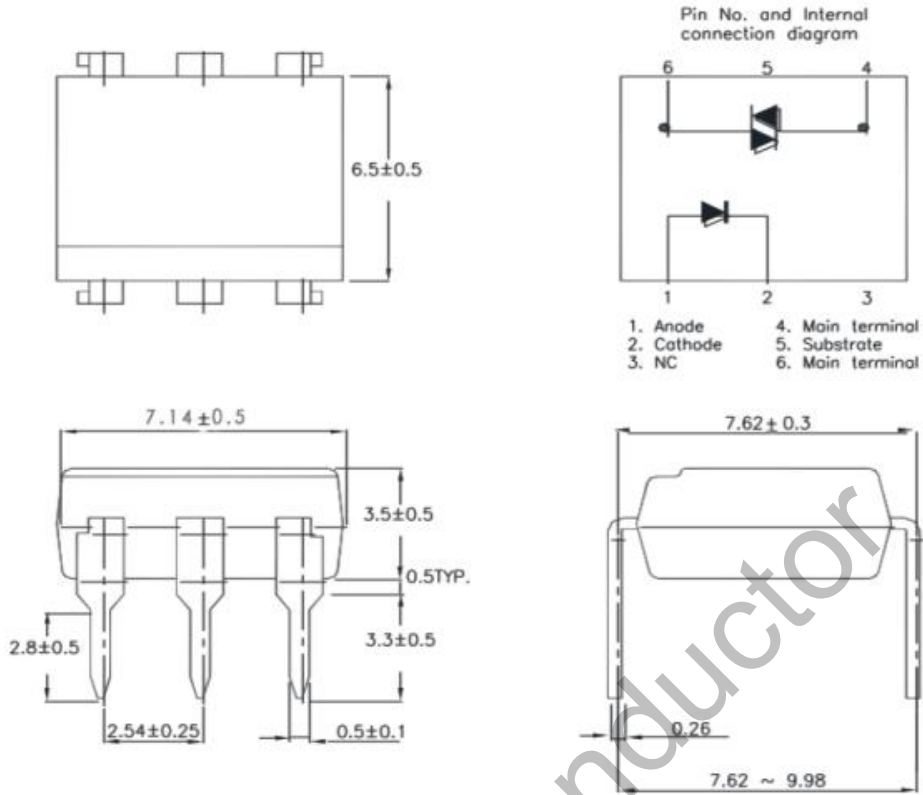
\*2. This is static dv/dt. Commutating dv/dt is a function of the load-driving thyristor(s) only.

\*3. All devices are guaranteed to trigger at an  $I_F$  value less than or equal to max  $I_{FT}$ .

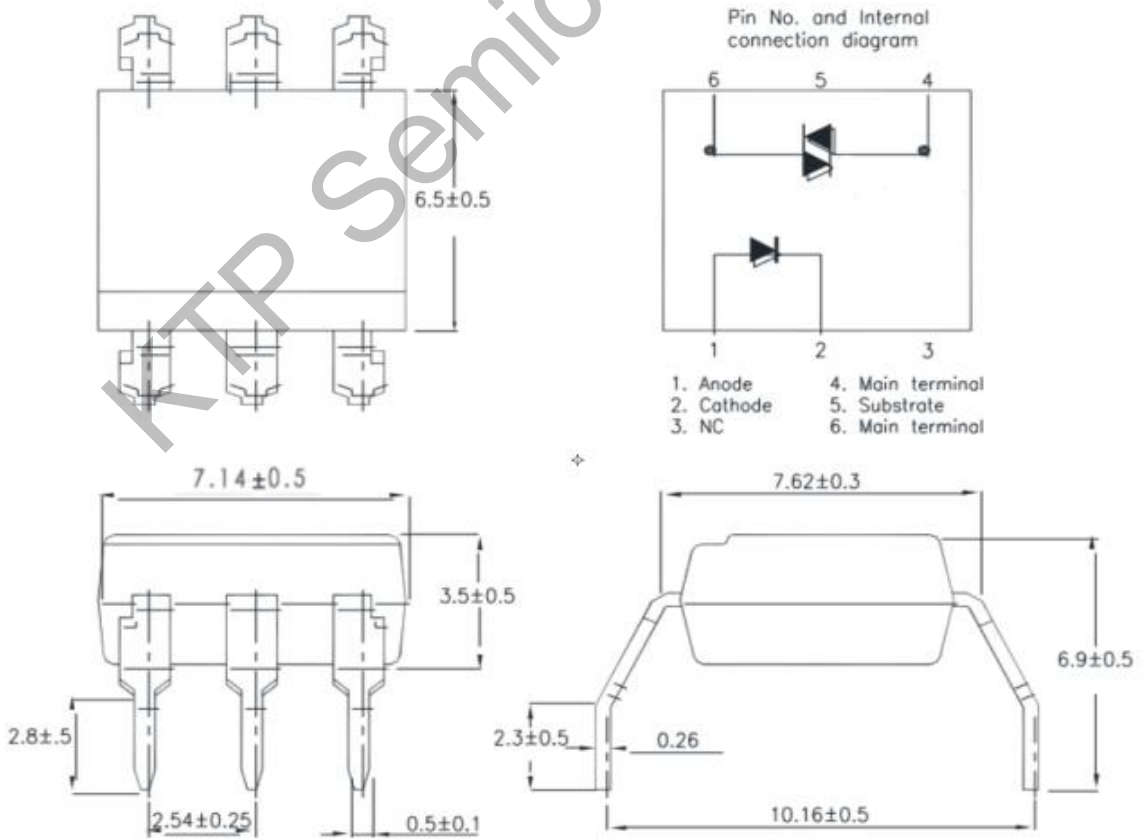
Therefore, recommended operating  $I_F$  lies between max  $I_{FT}$ , 30 mA for MOC3020, 15 mA for MOC3021, 10 mA for MOC3022, 5 mA for MOC3023, and absolute max  $I_F$  (50mA).

6. 外形尺寸 (Outer Dimension)

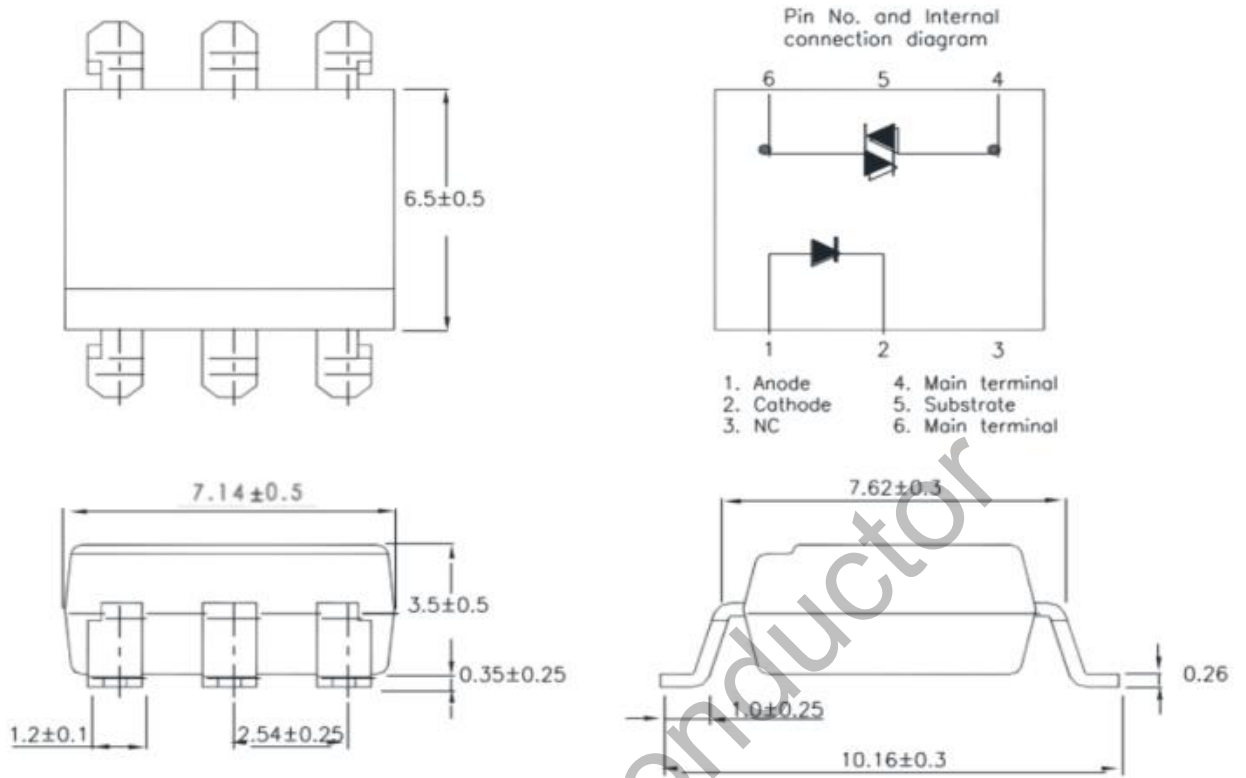
(1).MOC302X



(2).MOC302XM

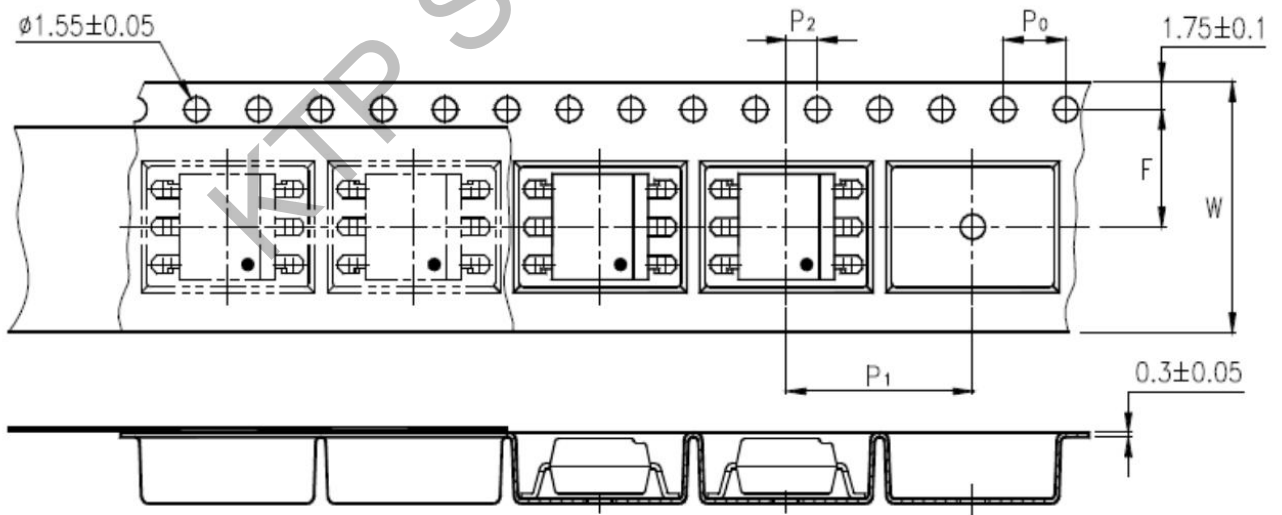


(3). MOC302XS

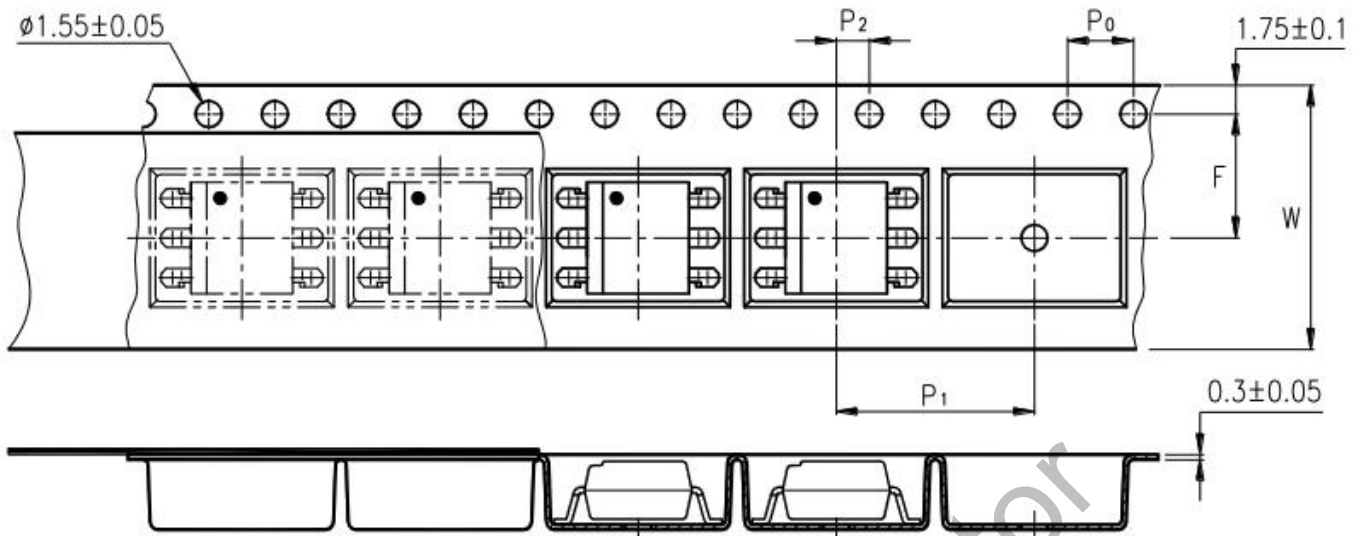


7. 编带尺寸 (Taping Dimensions)

(1). MOC302XS-TA



(2). MOC302XS-TA1



Description	Symbol	Dimension in mm (inch)
Tape wide	W	$16 \pm 0.3$ (0.63)
Pitch of sprocket holes	$P_0$	$4 \pm 0.1$ (0.15)
Distance of compartment	F	$7.5 \pm 0.1$ (0.295)
	$P_2$	$2 \pm 0.1$ (0.079)
Distance of compartment to compartment	$P_1$	$12 \pm 0.1$ (0.472)

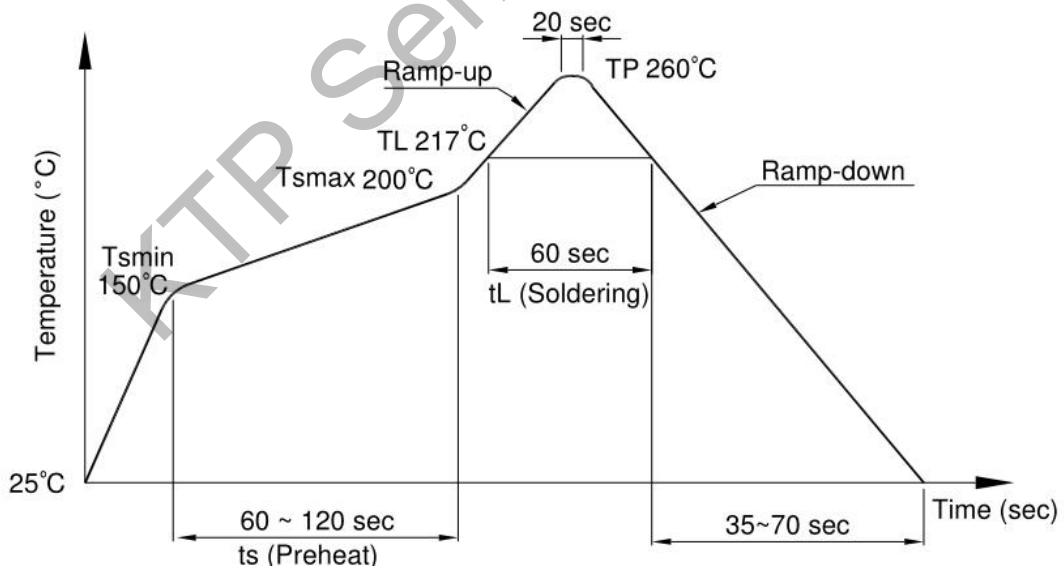
封装类型	MOC302XS series(TA/TA1)
数量 (个)	1000

8. 焊接温度曲线 (Temperature Profile Of Soldering)

(1). 红外回流焊 (jedec-std-020c 兼容) (IR Reflow soldering (JEDEC-STD-020C compliant))

注意：一次焊接回流建议在温度和时间配置文件如下所示的条件下。不要焊接超过三次。

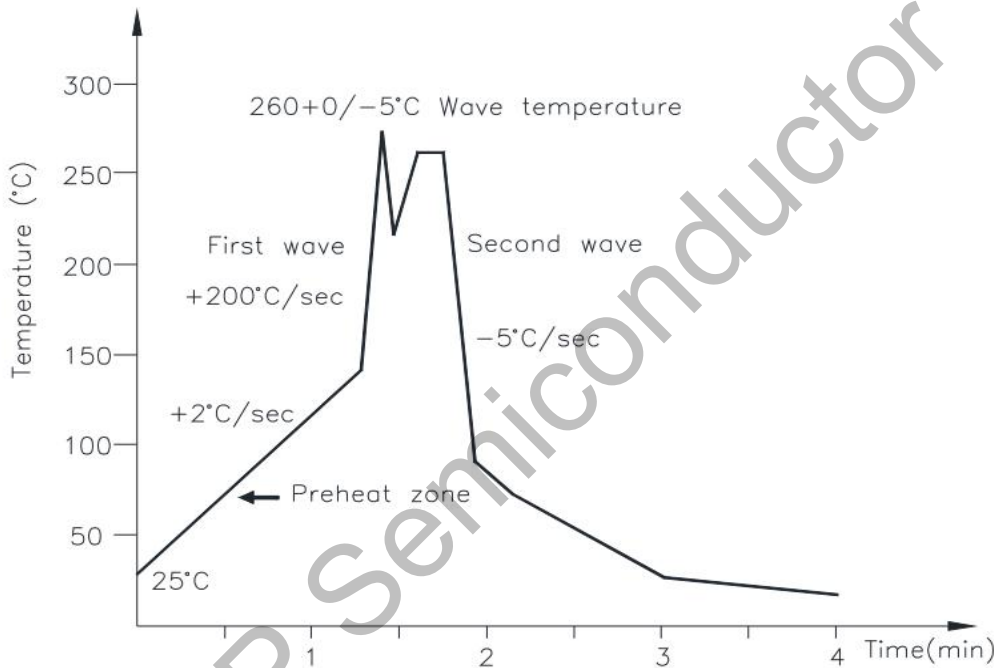
配置项	条件
预热 (Preheat)	
-最低温度 (TSmin)	150°C
-最高温度 (TSmax)	200°C
-时间 (最小到最大 (TS))	90±30 sec
焊接区 (Soldering zone)	
-温度 (TL)	217°C
-时间 (tL)	60 sec
峰值温度 (Peak Temperature)	260°C
爬升率 (Ramp-up rate)	3°C / sec max.
下降率 (3°C / sec max.)	3~6°C / sec



(2).波峰焊接 (jedec22a111 兼容) (Wave soldering (JEDEC22A111 compliant))

建议在温度条件下一致性焊接。

温度 (Temperature)	260+0/-5°C
时间 (Time)	10 sec
预热温度 (Preheat temperature)	5 to 140°C
预热时间 (Preheat time)	30 to 80 sec



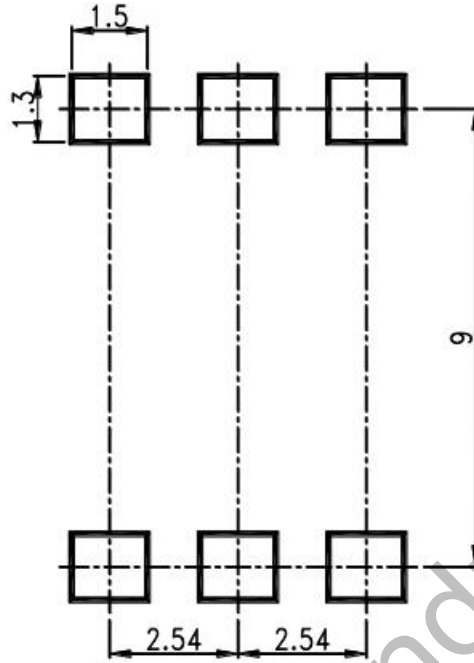
(3).电烙铁手工焊接 (Hand soldering by soldering iron)

允许单铅焊接在每一个过程中, 建议一次性焊接。

温度 (Temperature)	380+0/-5°C
时间 (Time)	3 sec max

9. 推荐的焊盘 (RRECOMMENDED FOOT PRINT PATTERNS (MOUNT PAD))

Unit: mm



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10. 特性曲线 (Characteristics Curve)

Fig.1 Forward Current vs. Ambient Temperature

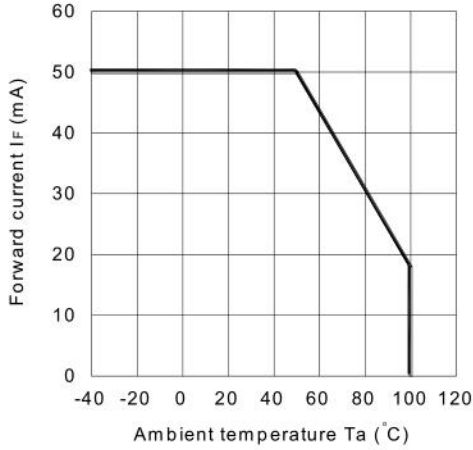


Fig.2 On-state Current vs. Ambient Temperature

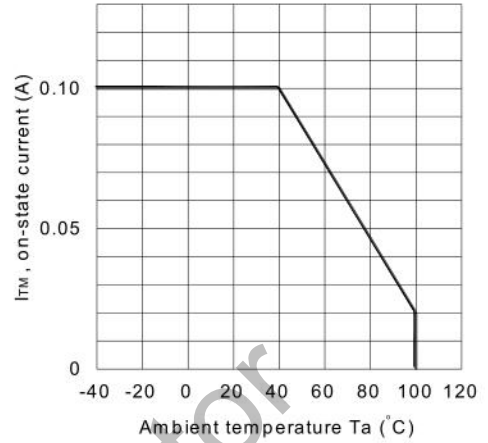


Fig.3 Minimum Trigger Current vs. Ambient Temperature

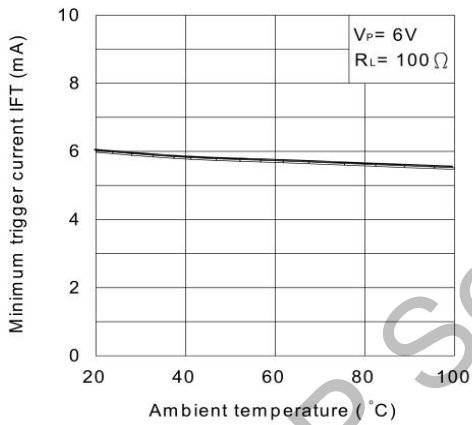


Fig.4 Forward Current vs. Forward Voltage

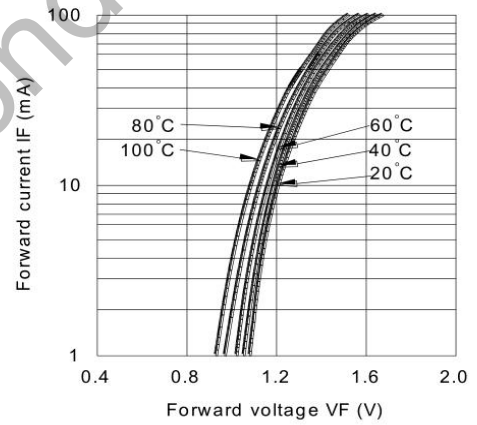


Fig.5 On-state Voltage vs. Ambient Temperature

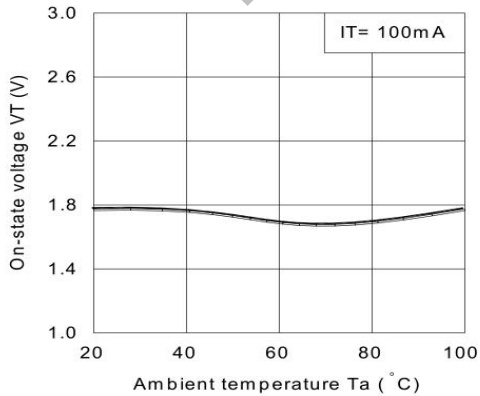


Fig.6 Holding Current vs. Ambient Temperature

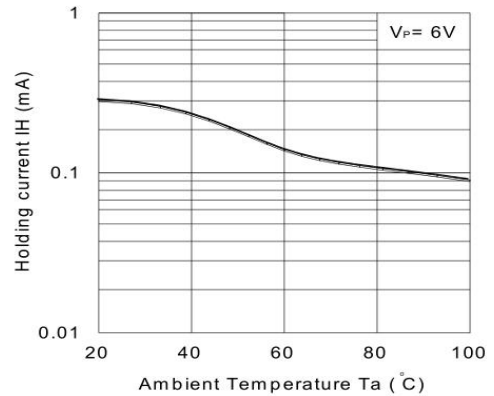


Fig.7 Repetitive Peak Off-state Current vs. Temperature

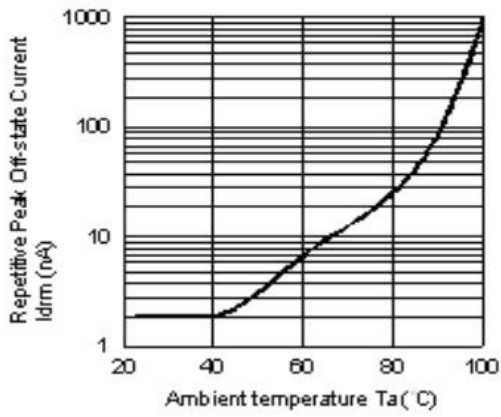
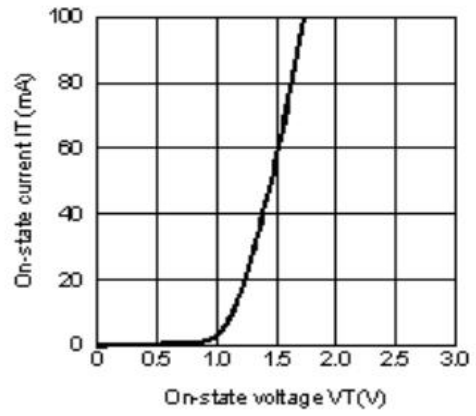
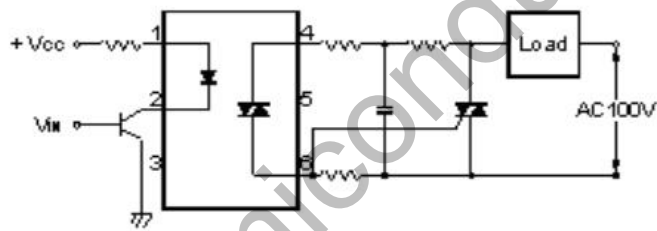


Fig.8 On-state Current vs. On-state Voltage



Basic Operation Circuit  
Medium/High Power Triac Drive Circuit



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